Operation of Superconducting Linear Accelerator and design of proposed Light Source at Delhi (LSD)

Subhendu Ghosh Inter University Accelerator Centre, New Delhi

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Outline

- 1. Superconducting Linac
 - Quarter Wave Resonators, cryostats etc.
 - Linac operation and latest results
 - A few interesting challenges in linac operation
- 2. Existing SRF Technology
 - Infrastructures and fabrication of QWRs at IUAC
 - Fabrication of 325 MHz Single Spoke resonators for Project-X
 - Tesla type 1.3 GHz cavities
- 3. Delhi Light Source (DLS)
 - Phase-I Resonator, Laser system, Photocathode, Klystron status and parameter finalization
 - Phase-II Exploring stage, literature survey, Collaboration



History of IUAC

Formerly (Nuclear Science Centre)

Before July, 1986









Inter University Accelerator Centre (*The first Inter-University Centre of UGC*)

- Established in 1984 as an autonomous institution funded by Indian Government
 - Accelerator facility operational by 1991

Objectives:

To provide world class accelerator system along with experimental facilities

To create basic infrastructure to facilitate internationally competitive research

Anybody from any university, IIT, NIT, or any other institutes, in India or abroad can be user





Activities of the Centre

- Development & Operation of Accelerator
 - 15 UD Pelletron Accelerator & Superconducting Linac
 - Low Energy Ion Beam facility
 - 1.7 MV Pelletron Accelerator
 - High current Injector Under Construction
 - Free Electron Laser a light source Planning stage
- Research using Ion Beams
 - Nuclear Physics, Material Science, Atomic Physics, Radiation Biology, Accelerator Mass Spectrometry
- Programs at under/post graduate and Ph.D. levels
 - ➢ 5-6 weeks Summer project (B.Sc.), 3 weeks M.Sc. Orientation Programme
 - Recruitment of Ph.D. students and fresh M.Sc. as employee
 - Local guidance for the Ph.D. students registered elsewhere

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Ion beam accelerators –

presently operational



Layout of the Accelerator system of IUAC



MAG

Major components of Linac

- Niobium Quarter Wave Resonator (QWR)
- Cryostats and cryogenics (LHe and LN₂)
- RF electronics (to power, phase and amplitude locking etc.)
- Beam transport elements





Niobium Resonators





Linac Cryostats



Niobium Quarter Wave Resonator (QWR)







echanical Tuner (Nb)



SS-jacketed Nb QWR

QWR schematic

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Cryostats and Cryogenics











Cryostats and Cryogenics

A Linac cryostat with 8 resonators and a solenoid magnet





Linear accelerator systems





SC Linac operation & Beam Acceleration

- All 5 cryostats (SB, 3 Accelerating and RB) are operational
- 1st. and 2nd. accelerating modules are having all 8 QWRs
- Third accelerating mod. 6 QWRs, 2 will be installed soon
- Cold test and beam acceleration with all five cryostats took place during April June 2014.





Challenges in Superconducting Linac operation





Challenges in Linac operation

• Experiments of vibrational damping on Quarter Wave Resonators



Frequency excursion (Δf) of a niobium resonator at room temperature without and with few tens of SS-balls.





Physical explanation behind Damping





Challenges in Linac operation

• Experiments of vibrational damping on Quarter Wave Resonators



Challenges in superconducting Linac operation



Challenges in superconducting Linac operation

• All gas based tuner of cryostats - 2/3 being replaced by Piezo based tuner

Cavities	With Gas based tuner (2012- 13)			With Piezoelectric actuator based tuner (2014)			ctuator 4)	
	Locking Field @ 4-6W	Phase stability	Amplitude stability	RF Power (Maximum)	Locking Field @ 4-6W	Phase stability	Amplitude stability	RF Power (Maximum)
R22	2.3	± 0.2°	0.7%	120 W	2.98	± 0.1 ⁰	0.03%	90 W
R24	2.57	± 0.5°	0.7%	120 W	3.17	± 0.1 ⁰	0.015%	100 W
R25	2.22	± 0.1 ⁰	0.16 %	130 W	2.30	± 0.03 ⁰	0.01%	100 W
R28	2.9	± 0.1 ⁰	0.1%	100 W	2.9	± 0.05°	0.03%	80 W
R33	2.42	± 0.3 ⁰	0.1%	120 W	2.73	± 0.05°	0.02%	90 W









Strengths Available

(existing facilities, expert manpower and infrastructure setup)

EBW



60kV, 250mA, 2x1x1 metre

HVF





EP, DI water plant, US bath, HPR



All mechanical works, e.g. forming machining etc. are performed by a commercial vendor, with whom we closely work.

Test Cryostat



♦ 600 mm × 1000 mm

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SRF infrastructure at IUAC – Cryogenic resources

OLD REFRIGERATOR Capacity ; 500 W at 4.2 K





CRYOGENIC CONTROL ROOM

NEW REFRIGERATOR CAPACITY : 1 KW at 4.2 K





HELIUM PURIFIER



HELIUM GAS STORAGE

Inter University Accelerator Centre, New Delhi



Schematic of Helium Cryo - Network of Superconducting LINAC





Liquid Helium Distribution Line







REBUNCHER

Inter University Accelerator Centre, New Delhi





Fabrication and testing of QWR at IUAC







Central Conductor & Housing



Electropolished Niobium Central Conductors



Mechanical Tuner



Electropolished niobium Top Flanges (top middle), major Assemblies of the QWRs (above) and Slow Tuner bellows (left).



Fabrication and Testing of QWR at IUAC

Resonators



Mechanical Tuner



Superconducting Niobium Quarter Wave Resonators (left) and Nb Slow Tuner bellows (above), built at IUAC for the Superconducting Linac.



Fabrication and Testing of QWR at IUAC



Accelerating gradient E_a at 4.2 K achieved in different QWRs indigenously built at IUAC, for the Superconducting Linac.

Resonator Q as a function of the accelerating gradient E_a at 4.2 K (for QWR # 4).



Design and development of Low beta Resonator

High Current Injector - HCI



Inter University Accelerator Centre, New Dell

Design and development of Low Beta Resonator





Design and development of Low beta Resonator











Prototype low beta resonator to be tested soon



Fabrication of Single Spoke resonator for Project-X

IUAC is presently constructing two SSR1 niobium resonators.



SSR1 - β =0.22, 325 MHz, Niobium Assembly



Fabrication of Single Spoke resonator for Project-X



Shell with Coupler Ports



End Wall assembly



Electropolished End Wall



Spoke assembly after electropolishing.

Present status

- Two outer shell assemblies and the end walls are electropolished
- Spoke to shell collar transition EBW is done
- End walls to be welded with shell



Tesla Type 1.3 GHz Single cell cavity



Gradient (MV/m)



Accelerating gradient achieved in Cavity #3 & 4

- Formed and machined at RRCAT
- Electron beam welded at IUAC
- EPed and surface treatment at ANL/Fermilab
- Tested at Fermilab



A niobium Single cell Cavity



Tesla Type 1.3 GHz multi cell cavity



- Will be formed/machined RRCAT
- To be beam welded at IUAC
- To be EP'ed and surface treatment at ANL/Fermilab
- To be tested at Fermilab

Fabrication of 650 MHz Single cell cavities for Project-X - Future

- Will be formed/machined at RRCAT
- To be beam welded at IUAC
- To be EP'ed and surface treatment at ANL/Fermilab
- To be tested at Fermilab



Layout of Delhi Light Source (DLS)





2.6 cell, S-band resonator Frequency = 2860 MHz Q-value (expected) ~ 15000







Details of Photocathode







Figure 1: General setup of a photoinjector (picture of the gun by courtesy of K. Floettmann, DESY Hamburg)

Courtsey: Prof. Junji Urakawa

MAG

Details of Photocathode

Photocathode:

- Metal Photocathode e.g. Copper, Magnesium, Lead
- Semiconductor photocathode e.g. Cs₂Te, K₂CsSb, GaAs

To be developed at IUAC

Cathode	Quantum Efficiency (%)	Photon Energy (eV)	Photon wavele ngth (nm)	Advantage	Disadvan tage	Laser Energy for 1 nC/pulse (~ 10 ⁹ e/pulse)
Copper	0.014	4.96 eV	250	Puggad	Less QE,	35.4 µJ
Magnesium	0.62	4.66 eV	266	Long life,	High	9.2 μJ
Lead	0.016	5.8 eV	214	Less vac	energy	2.2 μJ
Cs ₂ Te	~10	4.66 eV	266	High OF	Delicate,	51 nJ
K ₂ CsSb	~10	2.33 eV	533	Less laser	Shorter	23.3 nJ
GaAs:Cs	~10	2.33 eV	533	Energy	UHV	23.3 nJ
GaN:Cs Thin layer of Cesium is deposited on GaN	~15	4.77 eV	260	V. High QE robust (thk ~ 100-1000nm), QE is 50% back after 200C vac bakeout	New PC, not much data av.	37 nJ

• Cathode thickness ~ 100 nm, surface roughness \leq 10-20 nm

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Phase-I: A pre-bunched FEL (BRNS/IUAC funded)



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 $B_{\rm II}$ – Undulator mag field

Laser – tentative specifications

Aim is to produce 0.1 nC e-charge /laser pulse @ 266 nm, Pulse width ~ 100-200 fs

- 100 pC/micro-pulse means = $100 \times 10^{-12} / 1.6 \times 10^{-19} = 6.25 \times 10^8$ electrons
- If QE = 0.5% (worst case), $1.56 \times 10^{11(b)}$ photons are necessary to produce 6.25×10^8 electrons
- Energy of a photon, E = hv, $7.5x10^{-19(a)}$, Total energy per pulse = (a) x (b) ~ 116 nJ/pulse
- Single laser splitting into 16 pulses, so energy per pulse (minimum) = 0.116 x 16 ~ 2 μJ/pulse
 With a safety factor of 5, energy per pulse = 10 μJ/pulse
- Conversion from IR (800 nm) to UV (266 nm) power down-conversion is 5%
- Minimum Laser power (800 nm) ~ 200 µJ/pulse
- If the frequency of the rep rate is 10 Hz/10 KHz, power required @ 1066 nm = 2 mW / 2 W



Recommended Laser system for FEL (RT PI)

	The Laser system of AT	is based on T	i:Sa Oscillato	r
high-brightness	Wavelength	800 nm		
(low emittance) selonoid 1.3 GHz electron bunches	Reference Frequency	130 MHz		
bucking (sent into the linear accelerator)	Oscillator Frequency	130 MHz		
Cs ₂ Te photo cathode	Pulse duration	< 20 femto-s	ec	
	Model Name	Trident - X	Trident - C	Trident - M
Photocathode laser Converters IR > UV	Repetition rate	10 Hz	100 Hz	Multi KHz
laser pulse shaper oscillator $\lambda = \lambda = \lambda = \lambda = \lambda = \lambda = 1047 \text{ cm}$	Energy per pulse	\leq 25 mJ	$\leq 10 \text{ mJ}$	\leq 3 mJ
Figure 1: General setup of a photoinjector	Stability	<1.5% rms	< 1.2% rms	< 0.8% rms
(picture of the gun by courtesy of K. Floettmann, DESY Hamburg)	ASE contrast	>10 ⁵ .1		
Laser Osc. (130 MHz, 7.69 ns, 100 fs, $\lambda = 1 - 0.78 \mu m$) Single pass e-beam, low frequency (10 Hz) Freq c (IR to be compared to the second s	idth < 4 ns, 00 Hz plifier 7.7 ns onverter o UV) Gun	Pulse period Pulse width ≤ 4 ns	S	
gun	八			<u>_</u>

Tentative parameters for the THz facility at IUAC (modified)

Beam Parameters:		Radiation & Undulator Paramet	ers:
Electron Energy (MeV)	7	Radiation wavelength (µm)	150
Charge / Pulse (pC)	100	K-parameter	0.8
E-beam bunch length (fs)	300	Undulator period (cm) [5]	3.4
No. of micro-bunches (300fs each)	16	RMS strength (Tesla) [6]	0.25
Frequency of micro-bunch trains (Hz)	10	Number of periods (N) w 1m undultr	30
Peak current (Amp) [1]	333	Peak radiation power (MW) [7]	15
Peak beam power (GWatts) [2]	2.3	Average radiation power (mW) [8]	0.75
Average beam current (nA) [3]	16	Peak no. of photons [9] / 200 fs	10 ²⁸
Average beam power (watts) [4]	0.112	Average no. of photons / sec [10]	1017
$[1]\frac{100pC}{300\times10^{-15}} = 333A$	[5]150×10 ⁻⁶	$f = \frac{\lambda_u}{2\gamma^2} [1 + K^2] \Longrightarrow \lambda_u \approx 34mm \qquad [9] \frac{23.3 \times 10^6}{h\nu} = 1.7$	′6×10 ²⁸
[2] 333A x 7 -MV = 2.3 GW	$[6]0.8 = \frac{e \times e^{2}}{2 \times e^{2}}$	$\frac{a B_u \times \lambda_u}{\pi \times m \times c} \Rightarrow B_u = 0.25T \qquad [10] \frac{0.75 \times 10^{-3}}{hv} = 5$	5.68×10
	$L/J Pout \approx$	$\overline{5N}^{F} beam = \frac{150}{150} \times 2.5 \times 10^{-1} \approx 15 MW$	

[3] $100pC \ge 16 \ge 10 Hz = 16 nA$

[4] 16 nA x 75 MV = 112 mWatts

 $[8]P_{out} \approx \frac{1}{5N}P_{beam} = \frac{1}{150} \times 0.112 = 0.75mW$



Reference clock distribution system of FEL



Superconducting electron gun (DST & IUAC funded)

3.6 cell 1.3 GHz SC gun Final Energy ~ 8 Mev



QWR (130 MHz) SC RF gun + 5 cell 1.3 GHz Final Energy ~ 10 MeV

Advantage of 1.3 GHz resonator over 130 MHz QWR

- Much more matured technology
- Already in operation
- Technical knowhow exists
- Acquired knowledge will be useful for making 9 cell resonator, has to be made anyway

To develop knowledge on:

- Cavity (3.5 cell) and cryostat fabrication
- Handling of 2K LHe and other cryogenics details
- Indep. tuning mechanism of gun and accel. cells
- Design of the choke filter
- Design of HOM and input couplers



Courtsey: A.Arnold et. al, NIM A 577 (2007) p. 440



Superconducting electron gun (DST & IUAC funded)

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QWR RF gun followed by 5 cell 1.3 GHz Energy from QWR ~ 2 MeV

- Frequency of the resonator $\sim 130 \text{ MHz}$
- Structure Double walled Niobium QWR
- Energy obtained $\sim 2 \text{ MeV}$
- To be followed by 1.3 GHz \sim 5 cell, Final energy \sim 10 MeV



Superconducting electron gun (To be funded by DST & IUAC)





Advantage of low frequency resonator over higher frequency resonator

- Cryoplant operation at 4.2 K
- Small accelerating gap in comparison to the λ_{RF} so electric field is practically dc (T₁₃₀ ~ 7.69ns, T₁₃₀₀ ~ 0.769ns)
- Reduced RF losses @ PC (dielectric loss ~ f, skin effect ~ sqrt(f)
- High power, inexpensive CW source and RF couplers available
- Improved photocathode lifetime & less MP

Disadvantage:

- Still not used for operation
- Chances of failure ???





Collaboration, MoU etc.

Strategy:

- Collaborative institute should have their individual benefit
 - Should identify areas with common interests
 - Clarify each other's requirement/expectation
- IUAC's requirement:
- Develop SC 1.3 GHz, accelerate e-beam
 - Fabrication of cavity, Surface preparation, vertical test, fabrication of cryostat and final testing
 - Production of high quality e-beam, different diagnostic
- Develop undulator and produce e.m. radiation
 - Design, Fabrication/procurement of Undulator
 - Production of em radiation & diagnostic/measurement
 - Transport and delivery of the beam for experiment
- Start developing an user base (presently for THz)



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Collaboration, MoU etc.

What IUAC can offer:

• In Accelerator development:

- Provide manpower to work in Host Institute's accelerator project
- Gain experience while working and apply that at DLS
- IUAC can develop multiple components, for host/guest institutes
- In the field of Experiments etc.:
 - IUAC can form a researcher's group in India. They jointly propose some experiments in host institutes. Indian researcher/students can work in developing beam line, expt. setup etc.
 - Researcher from host institutes can participate in expts at IUAC



Conclusion

- > IUAC has taken up a project to develop a compact Light source
- Project has got three parts -
 - > Development of RT e-gun and produce THz
 - Development of SC e-gun and produce high power THz
 - Development of 1.3 GHz 9 cell cavity, increase the e-energy & produce IR and X-rays (ICS)
- For development of SC RF gun and 1.3 GHz 9 cell cavity, IUAC wants to collaborate. SRF technology exists at IUAC.
- For development of user base, IUAC wants to train Indian researcher in the field of photon science









Phase-I: A pre-bunched FEL (BRNS/IUAC funded)





Beam optics design for the RT e-Gun

Requirements for the first phase of the project: Beam energy(E): 8 MeV Spread (Δ E)~1% (~80keV) Bunch charge : 0.2 nC Bunch width: 0.2ps Normalized transverse emittance: ~1 π mm-mrad Tranverse beam size at the undulator ~250µm

Initial design calculations being done using ASTRA (A Space Charge Tracking Algorithm).

A tentative list of the essential beam line components with their approximate positioning are being prepared.



Beam optics design for the proposed light source facility (RT e-Gun)

Preliminary trial runs with ASTRA (to understand the working of the code)

Beam line configuration used in trials





Beam optics design for the RT e-Gun

Optimizations:

Laser Injection phase= 21° Accelerating field in 2.6 cell RF cavity= 120 MV/m Solenoid field=0.238 T Solenoid position=0.16 m Solenoid field profile

Results:

Output beam energy=8.56 MeV Energy spread (Δ E)=41.5 keV Horizontal beam size (σ x)=0.1 mm Vertical beam size (σ y)=0.1 mm Normalized transverse emittance case 1 (ϵ x, ϵ y) ~ 1.05/1.04 π mm mrad radial Normalized transverse emittance case 2 (ϵ x, ϵ y)=1.49 / 1.37 π mm mrad gaussian Longitudinal beam emittance case 1 (ϵ z)= 3.348 π keV mm (mm @ 8.56 MeV = 3.3 ps) Longitudinal beam emittance case 2 (ϵ z)= 10.6 π keV mm



Klystron and modulator – purchase, installation, testing

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SI.	Parameter	Value	Remarks
1.	Rated Peak Output power	≥ 25 MW	
2.	Rated average Output power	≥ 20 KW	
3.	Central operating frequency	2860 MHz	2856 MHz klystron easily
			converted to 2860 MHz
4.	Bandwidth (-1 dB)	A few MHz	To be specified
5.	Maximum operating output RF pulse	4 µs	
	duration measured at 3dB points		
6.	Operating Pulse repetition rate	Up to 200 Hz	To be confirmed by expert

	Parameter	Value	Remarks
1.	Modulator Power peak	≥ 75 MW	
2.	Modulator Power average	≥ 20 kW	Decided by Pul Rep Freq (PRF)
3.	Pulse voltage	$\geq\!280~{\rm kV}$	
4.	Pulse Current	$\geq\!280~\text{A}$	
5.	Operating Pulse repetition rate	up to 200 Hz	PRF To be checked
6.	Pulse length (top)	~ 4 μs	

09-09-14



Challenges in superconducting Linac operation



Research with THz, IR and X-rays from FEL

Biological research:

- Tera Hertz: 1. Oncology skin cancer, [British J. Dermatology, 151:424-432, 2004]
 - 2. Molecular structure determination in drug research [Journal of Biological Physics, 29, 89–100 (2003)]
 - 3. Dentistry, Oral healthcare, Tissue ablation, Security surveilance
 - 4. Chemical and bioagent detection through THz spectroscopy
 - 5. Time resolved THz spectroscopy of protein folding, Expt. with Biochips, Food processing
- Infra-red : 1. Ablation Tissue, Bone, Fat, Cholesterol ester etc.
 - 2. Application in Neurosurgery
- X-rays: 1. Artificial leaf to produce Oxygen, proton, will provide a source of alternate fuel in future [Jan Kern et al. Science Express, published on line on 14 Feb 2013, DOI: 10.1126/science 1234273]
 - 2. Research in structural biology with single protein crystal 3D images from 2D [Nov. 2012, Science]

Research in Physical Sciences: [terahertz]

- Tera Hertz: 1. Research in Electro-optics building block of modern comm. & information processing
 - 2. Coherent quantum control control the quantum mech state of electron future quantum computing qubits
 - 3. Terahertz Rabi Oscillations
 - 4. THz time domain spectroscopy (TDS) and THz tomography started obtaining images
 - 5. Electron paramagnetic resonance (EPR) or Electron spin resonance (ESR) a technique to study material with the unpaired electron successfully done with T-rays

7. Terahertz dynamics in materials especially dynamics driven far from equillibrium

- 8. Photon assisted transport
- 09-09-14 9. Material Physics, Device Physics, Hightaltitude communication

Research with THz, IR and X-rays from FEL

Research in Physical Sciences:

- Infra-red: 1. Nonlinear Vibrational Spectroscopy in the condensed phase [PRL, 70, (1993), 2718]
 - (a) Vibrational photon echoes (b) Pump probe Experiment
 - 2. Condensed matter research in vibrational relaxation phenomena [Infrared Phys. 89, (1996), 297]
 - (a) Amorphous material (b) Nanostructures (c) Spintronics (d) Biomolecules
 - 3. Gas Phase IR spectr. IR resonance enhanced multi-photon ionization (IR-REMPI) [Infrared Phys. 89, (1996), 297]
 - (a) Fullerenes (b) Nanocrystals (c) Clusters and complexes (d) Biomolecules
 - 4. Materials analysis and processing [Ref. Photochemistry and Photobiology, 2005, 81, 711-735]
 - (a) 2-colour matrix-assisted laser desorption and ionization
 - (b) Mass spectrometry of complex environmental materials
 - (c) IR matrix-assisted pulsed laser evaporation of nucleotides



Problem I: Investigations on topology and internal motions in bio molecules(DNA, RNA, Protein).



Important for DNA, RNA and Protein

- The far-infrared region of DNA and RNA absorption spectra (2 300 cm⁻¹) reflects lowfrequency molecular internal motions.
- Resonant frequencies of such motions called phonon modes- strongly dependent on:
 - the **weak hydrogen bonds** of the double-helix base-pairs and **non-bonded interactions** between different functional groups.



Problem II: Carrier Mobility in Disordered Systems

In disordered Systems, such as amorphous semiconductor, organic semiconductors, polymer: Carrier mobility cannot be measured by conventional techniques, such as Hall effect, thermoelectric effect and time of flight.

THz Measurement is non-contact, all optical measurement, providing carrier concentration and frequency dependant mobility. The THZ signal can be correlated to carrier mobility as per the equation below

$$\mu = \frac{(\Delta T / T_o)h\nu(1+n)}{\eta eF(1-e^{-\alpha d})Z_o}$$

= Mobility

μ

η h

ν

n

е

F

 Z_0

- $\Delta T / To = Differential transmission$
 - = Photogeneration efficiency
 - = Planck's constant
 - = THz frequency
 - =Refractive index of substrate
 - =Electric charge
 - =Fluence
 - = Free space impedance



Phenomena at Terahertz (THz) Frequencies:

1 THz = 10^{12} Hz =1 ps = 300 μ m = 0.004 eV = 33.3 cm⁻¹

Molecular Physics



molecules

Plasma Physics



Gaseous and solid-state plasmas

Atomic Physics

Solid State Physics



Solid State Physics



Mobility in Disorder

BioPhysics



Biomolecules & proteins

System hter University Accelerator Centre, New Delh







Research opportunities with different radiations from Free Electron Laser

<u>Tera Hertz range - sub-millimeter radiation - 0.3 to 3 THz (10⁻¹² Hz)</u>

Ablation of biological macromolecules under the action of THz irradiation

- Ablation is defined as the removal of material from the surface of object due to vaporization, chipping, or other erosive processes. Ablation can be the transfer of biomacromolecules from solid surface to the aerosol phase under FEL THz irradiation.
- Terahertz irradiation excites non-covalent molecular bonds (including hydrogen bonds).
- Mild, non-destructive ablation has been demonstrated for various nucleic acids (phage DNA and plasmids), proteins, and enzymes.
- Radiation of wavelength from 110 µm to 240 µm can be used, while it is well-known that radiation about 150 µm is capable to excite out-of-the-plane deformation vibrations in intermolecular hydrogen bonds O-H...O and O-H...N.
- Selective dissociation of these bonds by means of FEL radiation makes it possible to transfer a biomacromolecule to the gas phase (aerosol) with the retention of intramolecular covalent bonds.
- This allowed development of a new method of mild and non-destructive ablation.



Research opportunities (Bioscience) with Free Electron Laser beam

A few interesting examples:

- 3. Research on Biomedical science to study life forms on different levels from biomolecules and subcellular structures up to whole organism, Ref [1]
- Advantage of FEL over biomedical laser technique:
 - Superior to regularly used classical laser sources in optimizing wavelength-dose-pulse structure pattern to various types of tissue ablation
 - Minimizing the adverse effects in photo-ablative surgical techniques. Ref [5]

	Molecule	Optimal ablation wavelength
Characteristic absorption	Water (OH stretch mode)	2.94 μm
bands of a few molecule	Protein (amide II band)	6.45 μm
(mid IR range)	Protein (amide I band)	6.10 - 6.12 μm
Testaine en	Stretch of Protein (C = O)	8.525 μm

Techniques

- Selection of optimal wavelength at which FEL radiation ablates a tissue → relative absorption of main tissue components, water, the mineral components and the specific proteins
- FEL laser irradiation can superheat tissue water, driving thermal vapor bubbles confined by tissue matrix and leading to tissue ablation, Ref [6,7,8]
- Absorption band of many tissues may not be strongest in mid-IR, however FEL ablation is efficient while minimizing collateral damage.
- Knowing the absorption spectra of a tissue, λ can be guessed to be suitable for optimal ablation
- Verification of test experiment on the sample needs to be conducted before final application 09-09-14 Inter University Accelerator Centre, New Delhi 63



Research opportunities (Bioscience) with Free Electron Laser beam

A few interesting examples:

- 3. Research on Biomedical science to study life forms on different levels from biomolecules and subcellular structures up to whole organism
- Successful experiments being done
 - Experiments are mostly done with mid IR range of wavelength ($1-10 \ \mu m$)
 - Cortical bone ablation highest mass removal occurred at $6.1 \mu m$, with least thermal injury, Ref [5,9]
 - Selective removal cholesterol ester in Carotid artery with 5.75 μ m of radiation, Ref[10]
 - Exploiting the wavelength range between 1.21 to 1.72 m, fat absorbs radiation more than water, selective damage of fat without damage to overlying epidermis and dermis. Ref[11]
 - Surgery in Opthalmology, Oncology, Neurosurgery
 - In Neurosurgery
 - Brain tumors infiltrate vast operative brain regions, not possible to remove it in conven method
 - Optical laser affect surrounding structures and reacts differently with denser (cortex) and thinner (white matter) portion of brain
 - FEL is expected to do the job efficiently to control damage / ablation mechansim by adjusting radiation parameters like wavelength, fluence and pulse time structure.
 - Researches are in full swing to develop new optimized techniques and devices



Research opportunities with different radiations from Free Electron Laser

Tera Hertz range - sub-millimeter radiation – 0.3 to 3 THz (10⁻¹² Hz)

Terahertz electro-optics

- Control of light propagation in materials and material structure by applying a DC or slowly varying AC fields
 - A powerful probe to understand the properties of materials being used as fundamental building block of modern communication and information processing.
- In place of dc or slowly varying electric fields, THz frequencies are applied
- THz frequencies exceed the relaxation rates of most of the interesting materials systems and THz radiation resonates with internal quantum mechanical transitions
- Results to enhanced modulation of incident light due to its variable absorption

- 1. Photochemistry and photobiology, 2005, 81, page, 711-735.
- 2. Nordstrom, et al. (1998) Excitonic dynamical Franz-Keldysh effect. Phys. Rev. Lett. 81, 457–460.
- 3. Carter, S. et. al. (2004) Terahertz electro-optic wavelength conversion in GaAs quantum wells: improved efficiency and room-temperature operation. Appl. Phys. Lett. 84, 840–842.



Ref:

Research opportunities with different radiations from Free Electron

Laser

Tera Hertz range - sub-millimeter radiation – 0.3 to 3 THz (10⁻¹² Hz)

Control of quantum mechanical states in solids – utility of quantum computing and IT

- In quantum structure of the semiconductor, the electron motion follows the oscillations of the THz fields for many cycles before it relaxes or is scattered
- "Quantum computing" relies on the control of the quantum mechanical states before they relax or loose their phase coherence.
- In the anticipated "quantum computer", information is stored as '<u>qubits</u>'.
 - Classical computer has memory made up of bits, where each bit represents either a one or a zero.
 - Quantum computer maintains a sequence of qubits.
 - 1 qubit can represent a one, a zero, or, crucially, any quantum superposition of these two qubit states;
 - 2 qubits can be in any quantum superposition of 4 states, 3 qubits can be in any superposition of 8.
 - A quantum computer with qubits can be in an arbitrary superposition of up to different states simultaneously whereas a normal computer that can only be in one of these states at any one time.
 - A quantum computer operates by setting the qubits in a controlled initial state that represents the problem at hand and by manipulating those qubits with a fixed sequence of quantum logic gates.
 - The sequence of gates to be applied is called a quantum algorithm.
 - The calculation ends with measurement of all the states, collapsing each qubit into one of the two pure states, so the outcome can be at most classical bits of information.

Ref: 1. Photochemistry and photobiology, 2005, 81, pp=711-735, 2. C. H. Bennett. and D. P. DiVincenzo, Nature (London)404,247(2000) 3. J. I. Cirac and P. Zoller, Nature (London)404,579(2000), 4. D.P. DiVincenzo, Science, New Series, Vol. 270, No. 5234 (Oct. 13, 1995), 255+261 – (very good for basic understanding)

Research opportunities with different radiations from Free Electron

Laser

<u>Tera Hertz range - sub-millimeter radiation – 0.3 to 3 THz (10⁻¹² Hz)</u>

THz Rabi Oscillations in isolated donors

- A 2-level system undergoes Rabi Oscillations when a high frequency field is sufficiently intense that it drives the system from the ground to the excited state and back down again before it loses quantum mechanical phase memory.
- These experiments showed that hydrogen atom like motional states of electrons, bound to donor impurities, can serve as model 'qubits'

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